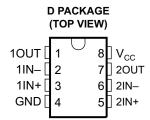
SLOS506-OCTOBER 2006

FEATURES

- Controlled Baseline
 - One Assembly/One Test Site, One Fabrication Site
- Extended Temperature Performance of -55°C to 125°C
- Enhanced Diminishing Manufacturing Sources (DMS) Support
- Enhanced Product-Change Notification
- Qualification Pedigree (1)
- Wide Supply Range:
 - Single Supply . . . 3 V to 30 V
 - Dual Supplies . . . ±1.5 V to ±15 V
- Low Supply-Current Drain, Independent of Supply Voltage . . . 0.7 mA Typ
- Common-Mode Input Voltage Range Includes Ground, Allowing Direct Sensing Near Ground
- (1) Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

- Low Input Bias and Offset Parameters:
 - Input Offset Voltage . . . 2 mV Typ
 - Input Offset Current . . . 2 nA Typ
 - Input Bias Current . . . 15 nA Typ
- Differential Input Voltage Range Equal to Maximum-Rated Supply Voltage . . . 32 V
- Open-Loop Differential Voltage Amplification
 . . . 100 V/mV Typ
- Internal Frequency Compensation



DESCRIPTION/ORDERING INFORMATION

The LM258A consists of two independent, high-gain, frequency-compensated operational amplifiers designed to operate from a single supply over a wide range of voltages. Operation from split supplies also is possible if the difference between the two supplies is 3 V to 30 V, and V_{CC} is at least 1.5 V more positive than the input common-mode voltage. The low supply-current drain is independent of the magnitude of the supply voltage.

Applications include transducer amplifiers, dc amplification blocks, and all the conventional operational amplifier circuits that now can be implemented more easily in single-supply-voltage systems. For example, this device can be operated directly from the standard 5-V supply used in digital systems and easily can provide the required interface electronics without additional ±5-V supplies.

ORDERING INFORMATION

T _A	V _{IO} max AT 25°C	MAX TESTED V _{CC}	PACKAG	iE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-55°C to 125°C	3mV	30V	SOIC - D	Reel of 2500	LM258AMDREP	258AM

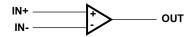
(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



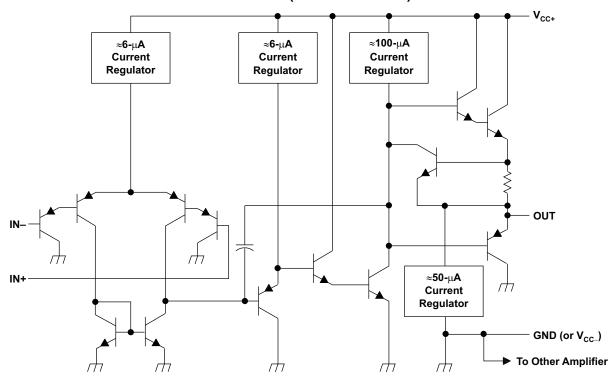
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SYMBOL (EACH AMPLIFIER)



SCHEMATIC (EACH AMPLIFIER)



COMPONENT	COUNT
Epi-FET	1
Diodes	2
Resistors	7
Transistors	51
Capacitors	2



DUAL OPERATIONAL AMPLIFIERS

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Absolute Maximum Ratings (1)

over operating free-air temperature range (unless otherwise noted)

		VALUE	UNIT
V_{CC}	Supply voltage ⁽²⁾	±16 or 32	٧
V_{ID}	Differential input voltage (3)	±32	V
V_{I}	Input voltage (either input)	-0.3 to 32	٧
	Duration of output short circuit (one amplifier) to ground at (or below) 25°C free-air temperature $(V_{CC} \le 15 \text{ V})^{(4)}$	Unlimited	
θ_{JA}	Package thermal impedance (5)(6)	97	°C/W
T_A	Operating free-air temperature range	-55 to 125	Ô
TJ	Operating virtual junction temperature	150	°C
T _{stg}	Storage temperature range (7)	-65 to 150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential voltages and V_{CC} specified for measurement of I_{OS}, are with respect to the network ground terminal.
- Differential voltages are at IN+ with respect to IN-.
- (4) Short circuits from outputs to V_{CC} can cause excessive heating and eventual destruction.
 (5) Maximum power dissipation is a function of T_J(max), θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability. The package thermal impedance is calculated in accordance with JESD 51-7.
- (7) Long-term high-temperature storage and/or extended use at maximum recommended operating conditions may result in a reduction of overall device life. See http://www.ti.com/ep_quality for additional information on enhanced plastic packaging.

LM258A-EP **DUAL OPERATIONAL AMPLIFIERS**

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Electrical Characteristics

at specified free-air temperature, $V_{\rm CC}$ = 5 V (unless otherwise noted)

	PARAMETER	TEST CONDITION	ONS ⁽¹⁾	T _A ⁽²⁾	MIN	TYP ⁽³⁾	MAX	UNIT
		$V_{CC} = 5 \text{ V to } 30 \text{ V},$		25°C		2	3	
V_{IO}	Input offset voltage	$V_{IC} = V_{ICR(min)},$ $V_{O} = 1.4 \text{ V}$		Full range			4	mV
α_{IO}	Average temperature coefficient of input offset voltage			Full range		7	15	μV/°C
I _{IO}	Input offset current	V _O = 1.4 V		25°C		2	15	nA
'IO	input onset current	v _O = 1.4 v		Full range			30	IIA
$\alpha_{\text{I}_{\text{IO}}}$	Average temperature coefficient of input offset current			Full range		10	200	pA/°C
ı	Input bigg gurrent	V _O = 1.4 V		25°C		-15	-80	nΛ
I _{IB}	Input bias current	$V_0 = 1.4 \text{ V}$		Full range			-100	nA
V	Common-mode	V _{CC} = 5 V to Max		25°C	0 to V _{CC} – 1.5			V
V_{ICR}	input voltage range	V _{CC} = 5 V to Max		Full range	0 to V_{CC} – 2			V
		$R_L \ge 2 \ k\Omega$		25°C	V _{CC} – 1.5			
V _{OH}	High-level output voltage	V - 20 V	$R_L = 2 k\Omega$	Full range	26			V
	output rollago	V _{CC} = 30 V	$R_L \ge 10 \text{ k}\Omega$	Full range	27	28		
V _{OL}	Low-level output voltage	$R_L \le 10 \text{ k}\Omega$		Full range		5	20	mV
	Large-signal	V _{CC} = 15 V,		25°C	50	100		
A _{VD}	differential voltage amplification	$V_O = 1 \text{ V to } 11 \text{ V},$ $R_L \ge 2 \text{ k}\Omega$		Full range	25			V/mV
CMRR	Common-mode rejection ratio	$V_{CC} = 5 \text{ V to Max}$ $V_{IC} = V_{ICR(min)}$		25°C	70	80		dB
k _{SVR}	Supply-voltage rejection ratio $(\Delta V_{DD}/\Delta V_{IO})$	V _{CC} = 5 V to Max		25°C	65	100		dB
V _{O1} /V _{O2}	Crosstalk attenuation	f = 1 kHz to 20 kHz		25°C		120		dB
		$V_{CC} = 15 \text{ V},$	_	25°C	-20	-30	-60	
		$V_{ID} = 1 V,$ $V_{O} = 0$	Source	Full range	-10			
I _O	Output current	V _{CC} = 15 V,		25°C	10	20		mA
O		$V_{ID} = -1 \text{ V},$ $V_{O} = 15 \text{ V}$	Sink	Full range	5			1
		$V_{ID} = -1 \text{ V}, V_{O} = 200 \text{ m}$	V	25°C	12	30		μΑ
I _{OS}	Short-circuit output current	V_{CC} at 5 V, GND at -5 V $V_{O} = 0$	٧,	25°C		±40	±60	mA
	Supply current	$V_O = 2.5 \text{ V}$, No load		Full range		0.7	1.2	A
I _{CC}	(two amplifiers)	$V_{CC} = Max$, $V_O = V_{CC}/2$, No load	Full range		1	2	mA

 ⁽¹⁾ All characteristics are measured under open-loop conditions with zero common-mode input voltage, unless otherwise specified. MAX V_{CC} for testing purposes is 30 V.
 (2) Full range is -55°C to 125°C.
 (3) All typical values are at T_A = 25°C.



Operating Characteristics

 $V_{CC} = \pm 15 \text{ V}, T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST CONDITIONS	TYP	UNIT
SR	Slew rate at unity gain	$R_L = 1 \text{ M}\Omega$, $C_L = 30 \text{ pF}$, $V_I = \pm 10 \text{ V}$, See Figure 1	0.3	V/μs
B ₁	Unity-gain bandwidth	$R_L = 1 \text{ M}\Omega$, $C_L = 20 \text{ pF}$, See Figure 1	0.7	MHz
V _n	Equivalent input noise voltage	$R_S = 100 \Omega$, $V_I = 0 V$, $f = 1 kHz$, See Figure 2	40	nV/√ Hz

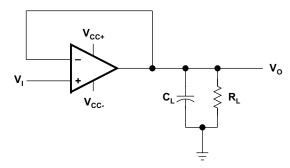


Figure 1. Unity-Gain Amplifier

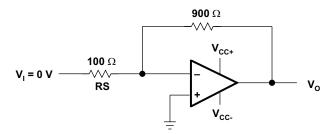


Figure 2. Noise-Test Circuit





.com 24-Oct-2008

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins F	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
LM258AMDREP	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LM258AMDREPG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
V62/07605-01XE	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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Catalog: LM258A

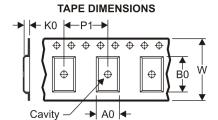
NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product



TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device		Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM258AMDREP	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1



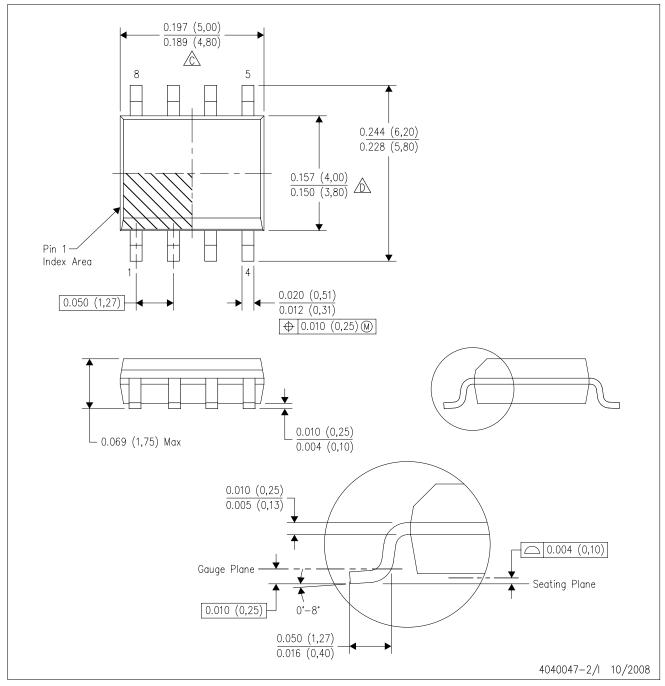


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM258AMDREP	SOIC	D	8	2500	346.0	346.0	29.0

D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AA.



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